NSN 5961-01-506-4910

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-506-4910 **Inclosure Material:** Metal **Overall Length:** 1.960 inches **Overall Height:** Between 0.610 inches and 0.700 inches **End Application:** Used in nsn 5895011226087, tornado aircraft **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-66 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 300.0 collector to emitter voltage/static/base open and 3.0 collector to emitter saturation voltage **Current Rating Per Characteristic:** 3.00 amperes all primaries **Power Rating Per Characteristic:** 30.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 25.0 static forward current transfer ratio, common-emitter and 75.0 static forward current transfer ratio, common-emitter **Product Name:** Npn triple diffused planar power transistor **Precious Material And Location:** Internal surfaces gold **Precious Material: Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Fiig:

A110a0